Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	13	(US-20020005473-\$ or US-20010001562-\$ or US-20050269482-\$).did. or (US-6043478-\$ or US-6150676-\$ or US-6423994-\$ or US-6160281-\$ or US-6856350-\$ or US-6927884-\$ or US-6163023-\$ or US-6950136-\$ or US-6483163-\$ or US-6590196-\$).did.	US-PGPUB; USPAT	OR	ON	2007/01/26 15:22
L2	2	L1 and (analog with digital with converter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/26 15:48
L3	68	(Shinohara-Mahito.IN.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/26 15:48
S1	2	"20040036789"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 08:16
S2	5	"6043478"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 15:53
S3	14	"6150676"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 15:53
S4	4	"2002005473"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 15:54

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S5	4	"2002005473"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 15:54
S6	2	"20020005473"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 16:24
S7	5259270	EP "0862219"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 16:25
S8	9	"0862219"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/01/24 16:27
S9	7	"6423994"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 16:28
S10	22	"6160281"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 16:28
S11	36	(348/281.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 08:16
S12	5	(US-20020005473-\$).did. or (US-6043478-\$ or US-6150676-\$ or US-6423994-\$ or US-6160281-\$).did.	US-PGPUB; USPAT	OR	ON	2007/01/25 08:30

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S13	8217	(Junction near Field near Effect near Transistor) or (JFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 09:05
S14	. 0	S12 and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 08:31
S15	0	((Junction same Field same Effect same Transistor) or (JFET)) and S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 08:32
S16	3442	(250/208.1.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 09:05
S17	54	(250/208.1.ccls.) and ((Junction same Field same Effect same Transistor) or (JFET))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:04
S18	179	(250/208.1.ccls.) and ((electric) with (potential))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:04
S19	978	(348/308.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:04
S20	47	(348/308.ccls.) and ((Junction same Field same Effect same Transistor) or (JFET))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/01/25 11:23
S21	0	("2004/0036789").URPN.	USPAT	OR	ON	2007/01/25 11:14

S22	108	(348/308.ccls.) and ((electric) with (potential))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:28
S23	1026	(257/292.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:29
S24	129	(257/292.ccls.) and (electric with potential)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON ·	2007/01/25 11:34
S25	66	(257/292.ccls.) and (@ad<="20020821") and (electric with potential)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:47
S26	362	(348/302.ccls.) and (@ad<="20020821")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:46
S27	274	(348/302.ccls.) and (@ad<="20020821") and (amplif\$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:46
S28	264	(257/292.ccls.) and (@ad<="20020821") and (amplif\$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2007/01/25 14:15
S29	1119	(250/208.1.ccls.) and (@ad<="20020821") and (amplif\$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:50

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S30	681	(250/208.1.ccls.) and (@ad<="20020821") and (amplif\$7) and (capacit\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 12:43
S31	444	(250/208.1.ccls.) and (@ad<="20020821") and (amplif\$7) and (capacit\$3) and (potential)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 13:02
S32	100	(250/208.1.ccls.) and (@ad<="20020821") and (amplif\$7) and (capacit\$3) and (electric same potential)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 12:44
S33	111	(250/208.1.ccls.) and (@ad<="20020821") and (amplif\$7) and (capacit\$3) and (potential) and (pixel with size)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 13:02
S34	4	"6836291"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 17:25
S35	447	(348/302.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 17:25
S36	333	(348/302.ccls.) and (amplif\$7)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 17:25
S37	274	(348/302.ccls.) and (amplif\$7) and (@ad<="20020821")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 17:26

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S38	149	(348/302.ccls.) and (amplif\$7) and (@ad<="20020821") and CMOS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 17:26
S39	53	(JFET) with advantage with (MOSFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/26 09:27